

2RI100G-160 SANREX IGBT MODULE

Model	2RI100G-160
Brand	SANREX
Category	SANREX
Component Type	Power Diode Module / Thyristor (SCR)
Maximum Average Forward Current (IT(AV) / IO)	100 A
Maximum Repetitive Peak Reverse Voltage (VRRM)	1600 V
Maximum Forward Voltage (VF)	1.4 V
Number of Elements / Phases	2 Elements, 1 Phase
Configuration	Series Connected, Center Tap
Max. Operating Junction Temperature (Tj)	150 °C
Mounting Type	Flange Mount
Package / Case	R-PUFM-X3 / TO-208
Material	Silicon
Manufacturer	Fuji Electric (Fujitsu)

Note:

Invshop recommends that you inquire with the original factory or its agents about the latest production status and technical information about 2RI100G-160. The product parameters displayed on Invshop are entered by Invshop engineers according to the specifications, and efforts have been made to minimize errors, but we cannot guarantee the complete correctness of the parameters. Please refer to the specification sheet!



2R160E-060





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